

5MHz, Low-Noise, Single, Dual, Quad CMOS Operational Amplifiers

Check for Samples: OPA377, OPA2377, OPA4377

FEATURES

- **GAIN BANDWIDTH PRODUCT: 5.5MHz**
- LOW NOISE: 7.5nV/VHz at 1kHz
- **OFFSET VOLTAGE: 1mV (max)**
- **INPUT BIAS CURRENT: 0.2pA**
- **RAIL-TO-RAIL OUTPUT**
- **UNITY-GAIN STABLE**
- **EMI INPUT FILTERING**
- QUIESCENT CURRENT: 0.76mA/ch
- SUPPLY VOLTAGE: 2.2V to 5.5V
- SMALL PACKAGES: SC70, SOT23, and MSOP

APPLICATIONS

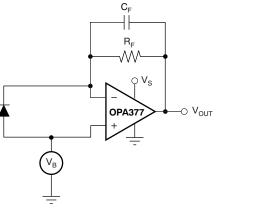
- PHOTODIODE PREAMP
- PIEZOELECTRIC SENSOR PREAMP
- SENSOR SIGNAL CONDITIONING
- AUDIO EQUIPMENT
- **ACTIVE FILTERS**



The OPA377 family of operational amplifiers are wide-bandwidth CMOS amplifiers that provide very low noise, low input bias current, and low offset voltage while operating on a low quiescent current of 0.76mA (typ).

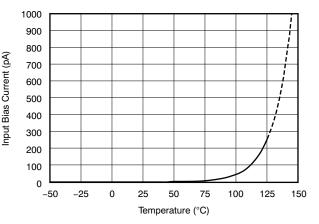
The OPA377 op amps are optimized for low-voltage, applications. single-supply The exceptional combination of ac and dc performance make them ideal for a wide range of applications, including small signal conditioning, audio, and active filters. In addition, these parts have a wide supply range with excellent PSRR, making them attractive for applications that run directly from batteries without regulation.

The OPA377 is available in the SC70-5, SOT23-5, and SO-8 packages. The dual OPA2377 is offered in the SO-8 and MSOP-8, and the quad OPA4377 in the TSSOP-14 packages. All versions are specified for operation from -40°C to +125°C.



Photodiode Preamplifier

INPUT BIAS CURRENT vs TEMPERATURE



 $\overline{\Lambda}\overline{\Lambda}$

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

OPA377 OPA2377 OPA4377 SBOS504B-FEBRUARY 2010-REVISED JANUARY 2011



www.ti.com



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ABSOLUTE MAXIMUM RATING⁽¹⁾

Over operating free-air temperature range, unless otherwise noted.

			OPA377, OPA2377, OPA4377	UNIT		
Supply Voltage $V_S = (V+) - V_S$		$V_{\rm S} = (V+) - (V-)$	+7	V		
Signal Input Terminals	Voltage ⁽²⁾		(V–) – 0.5 to (V+) + 0.5	V		
Signal input reminals	Current ⁽²⁾		±10	mA		
Output Short-Circuit ⁽³⁾			Continuous			
Operating Temperature		T _A	-40 to +150	°C		
Storage Temperature		T _A	-65 to +150	°C		
Junction Temperature		TJ	+150	°C		
	Human Body Model		4000	V		
ESD Rating	Charged Device Model		1000	V		
	Machine Model		200	V		

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.

(2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current limited to 10mA or less.

(3) Short-circuit to ground, one amplifier per package.

PACKAGE INFORMATION⁽¹⁾

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	PACKAGE MARKING
	SC70-5	DCK	OP377A
OPA377	SOT23-5	DBV	OP377A
	SO-8	D	OP377A
0040077	SO-8	D	O2377A
OPA2377	MSOP-8	DGK	OTAQ
OPA4377	TSSOP-14	PW	O4377A

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.



OPA377 OPA2377 OPA4377 SBOS504B-FEBRUARY 2010-REVISED JANUARY 2011

www.ti.com

ELECTRICAL CHARACTERISTICS: $V_s = +2.2V$ to +5.5V

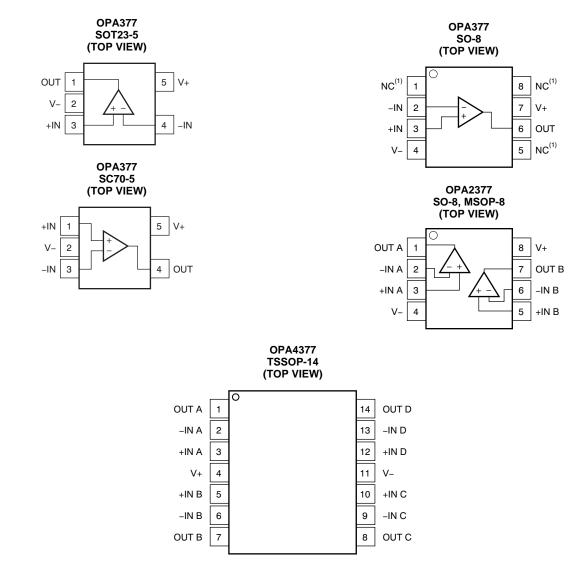
Boldface limits apply over the specified temperature range: $T_A = -40^{\circ}C$ to +125°C. At $T_A = +25^{\circ}C$, $R_L = 10k\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

				7, OPA2377, O		UNIT
PARAMETERS		CONDITIONS	MIN	MIN TYP MAX		
OFFSET VOLTAGE						
Input Offset Voltage	V _{OS}	$V_{S} = +5V$		0.25	1	mV
vs Temperature	dV _{OS} /dT	–40°C to +125°C		0.32	2	μ V/°C
vs Power Supply	PSRR	$V_{\rm S}$ = +2.2V to +5.5V, $V_{\rm CM}$ < (V+) – 1.3V		5	28	μV/V
Over Temperature		V_{S} = +2.2V to +5.5V, V_{CM} < (V+) – 1.3V		5		μ V/V
Channel Separation, dc (dual, quad)				0.5		μV/V
INPUT BIAS CURRENT	1					
Input Bias Current	Ι _Β			±0.2	±10	pА
Over Temperature			See T	ypical Charact		рА
Input Offset Current	I _{OS}			±0.2	±10	рА
NOISE	1					
Input Voltage Noise,	e _n	f = 0.1Hz to $10Hz$		0.8		μV _{PP}
Input Voltage Noise Density	en	f = 1kHz		7.5		nV/√Hz
Input Current Noise	i _n	f = 1kHz		2		fA/√Hz
INPUT VOLTAGE RANGE						
Common-Mode Voltage Range	V _{CM}		(V–) – 0.1		(V+) + 0.1	V
Common-Mode Rejection Ratio	CMRR	$(V-) < V_{CM} < (V+) - 1.3 V$	70	90		dB
INPUT CAPACITANCE						
Differential				6.5		pF
Common-Mode				13		pF
OPEN-LOOP GAIN						
Open-Loop Voltage Gain	A _{OL}	$50\text{mV} < \text{V}_{\text{O}} < (\text{V+}) - 50\text{mV}, \text{ R}_{\text{L}} = 10\text{k}\Omega$	112	134		dB
		$100mV < V_O < (V+) - 100mV, R_L = 2k\Omega$		126		dB
FREQUENCY RESPONSE		$V_{S} = 5.5V$				
Gain-Bandwidth Product	GBW			5.5		MHz
Slew Rate	SR	G = +1		2		V/µs
Settling Time 0.1%	t _S	2V Step , G = +1		1.6		μs
Settling Time 0.01%	t _S	2V Step , G = +1		2		μS
Overload Recovery Time		$V_{IN} \times Gain > V_S$		0.33		μS
THD + Noise	THD+N	$V_O=1V_{RMS},G=+1,f=1kHz,R_L=10k\Omega$		0.00027		%
OUTPUT						
Voltage Output Swing from Rail		$R_L = 10k\Omega$		10	20	mV
Over Temperature		$R_L = 10k\Omega$			40	mV
Short-Circuit Current	I _{SC}			+30/-50		mA
Capacitive Load Drive	C _{LOAD}		See	Typical Characte	eristics	
Open-Loop Output Impedance	R _O			150		Ω
POWER SUPPLY						
Specified Voltage Range	Vs		2.2		5.5	V
Quiescent Current per amplifier	Ι _Q	$I_{O} = 0, V_{S} = +5.5V$		0.76	1.05	mA
Over Temperature					1.2	mA
TEMPERATURE RANGE						
Specified Range			-40		+125	°C
Thermal Resistance	θ_{JA}					°C/W
SC70-5	1			250		°C/W
SOT23-5				200		°C/W
MSOP-8, SO-8, TSSOP-14				150	1	°C/W

TEXAS INSTRUMENTS

www.ti.com

PIN CONFIGURATIONS



(1) NC denotes no internal connection.

(2) Connect thermal die to V-.

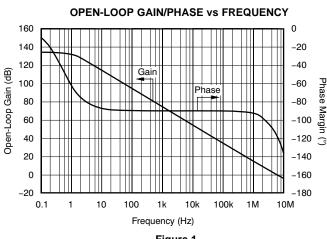


OPA377 OPA4377 SBOS504B-FEBRUARY 2010-REVISED JANUARY 2011

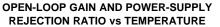
www.ti.com

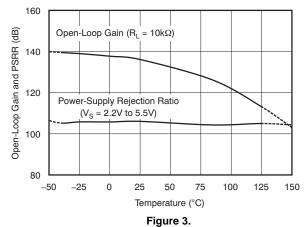
TYPICAL CHARACTERISTICS

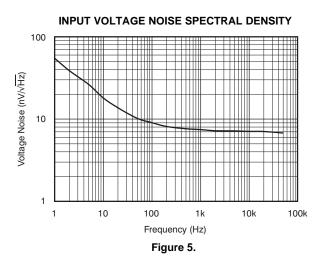
At $T_A = +25^{\circ}$ C, $V_S = +5$ V, $R_L = 10$ k Ω connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

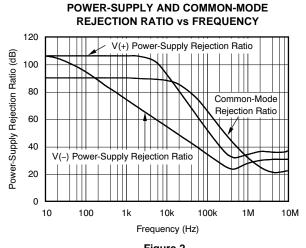






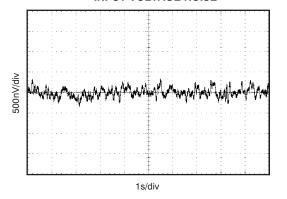




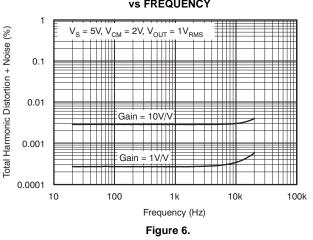




0.1Hz to 10Hz **INPUT VOLTAGE NOISE**







TOTAL HARMONIC DISTORTION + NOISE vs FREQUENCY

© 2010-2011, Texas Instruments Incorporated

OPA377 OPA2377 OPA4377

-50

Common-Mode Rejection Ratio (dB)

2.0

-50

-25

Input Bias Current (pA)

2.5

Quiescent Current (µA)

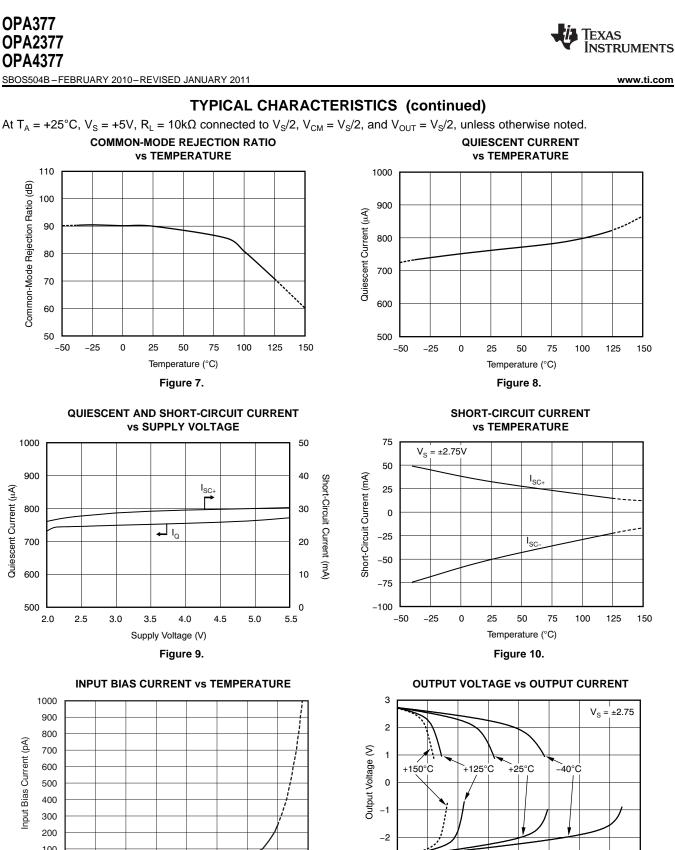
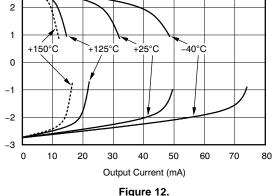


Figure 11.

Temperature (°C)



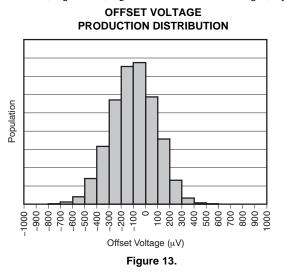


OPA377 OPA2377 OPA4377 SBOS504B – FEBRUARY 2010 – REVISED JANUARY 2011

www.ti.com

TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^{\circ}$ C, $V_S = +5$ V, $R_L = 10$ k Ω connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.



MAXIMUM OUTPUT VOLTAGE vs FREQUENCY

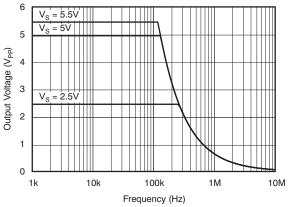


Figure 14.

SMALL-SIGNAL PULSE RESPONSE

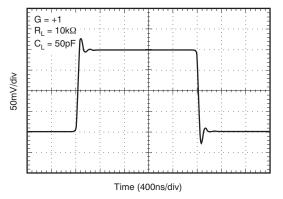
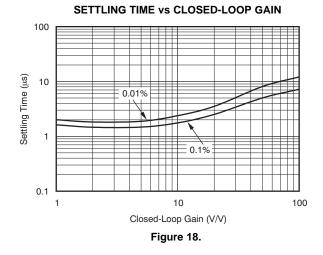
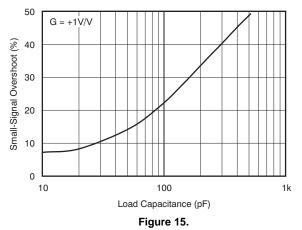
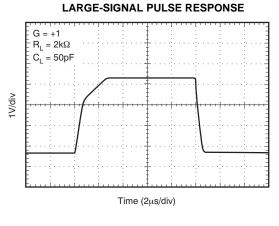


Figure 16.



SMALL-SIGNAL OVERSHOOT vs LOAD CAPACITANCE







OPA377 OPA2377 OPA4377 SBOS504B - FEBRUARY 2010 - REVISED JANUARY 2011

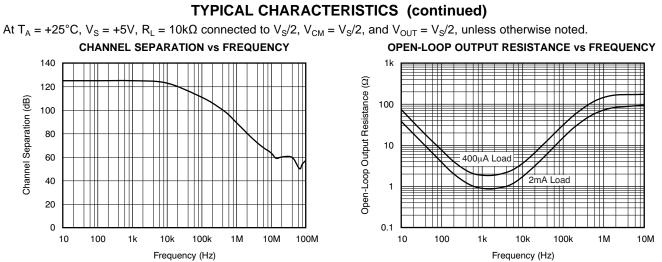


Figure 19.

www.ti.com

ISTRUMENTS

EXAS

Figure 20.

8



APPLICATION INFORMATION

OPERATING CHARACTERISTICS

The OPA377 family of amplifiers has parameters that are fully specified from 2.2V to 5.5V (\pm 1.1V to \pm 2.75V). Many of the specifications apply from –40°C to +125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the Typical Characteristics.

GENERAL LAYOUT GUIDELINES

For best operational performance of the device, good printed circuit board (PCB) layout practices are required. Low-loss, 0.1μ F bypass capacitors must be connected between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable to single-supply applications.

BASIC AMPLIFIER CONFIGURATIONS

The OPA377 family is unity-gain stable. It does not exhibit output phase inversion when the input is overdriven. A typical single-supply connection is shown in Figure 21. The OPA377 is configured as a basic inverting amplifier with a gain of -10V/V. This single-supply connection has an output centered on the common-mode voltage, V_{CM}. For the circuit shown, this voltage is 2.5V, but may be any value within the common-mode input voltage range.

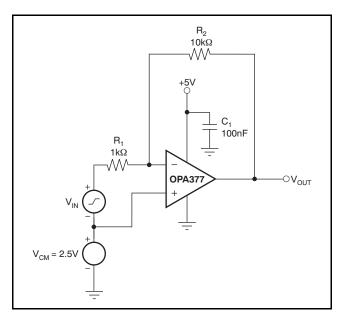


Figure 21. Basic Single-Supply Connection

COMMON-MODE VOLTAGE RANGE

The input common-mode voltage range of the OPA377 series extends 100mV beyond the supply rails. The offset voltage of the amplifier is low, from approximately (V–) to (V+) – 1V, as shown in Figure 22. The offset voltage increases as common-mode voltage exceeds (V+) –1V. Common-mode rejection is specified from (V–) to (V+) - 1.3V.

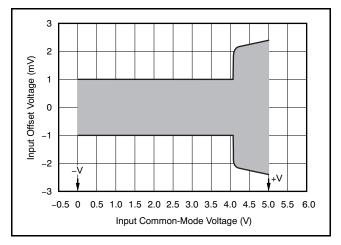


Figure 22. Offset and Common-Mode Voltage



INPUT AND ESD PROTECTION

The OPA377 family incorporates internal electrostatic discharge (ESD) protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current steering diodes connected between the input and power-supply pins. These ESD protection diodes also provide in-circuit, input overdrive protection, as long as the current is limited to 10mA as stated in the Absolute Maximum Ratings. Figure 23 shows how a series input resistor may be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and its value should be kept to a minimum in noise-sensitive applications.

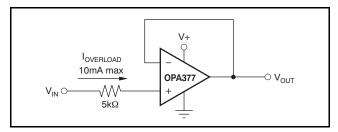


Figure 23. Input Current Protection

EMI SUSCEPTIBILITY AND INPUT FILTERING

Operational amplifiers vary in susceptibility to electromagnetic interference (EMI). If conducted EMI enters the operational amplifier, the dc offset observed at the amplifier output may shift from the nominal value while the EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. While all amplifier pin functions can be affected by EMI, the input pins are likely to be the most susceptible. The OPA377 operational amplifier family incorporates an internal input low-pass filter that reduces the amplifier response to EMI. Both common-mode and differential mode filtering are provided by the input filter. The filter is designed for a cutoff frequency of approximately 75MHz (-3dB), with a roll-off of 20dB per decade.

CAPACITIVE LOAD AND STABILITY

The OPA377 series of amplifiers may be used in applications where driving a capacitive load is required. As with all op amps, there may be specific instances where the OPAx377 can become unstable. leading to oscillation. The particular op amp circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether an amplifier will be stable in operation. An op amp in the unity-gain (+1V/V) buffer configuration and driving a capacitive load exhibits a greater tendency to be unstable than an amplifier operated at a higher noise gain. The capacitive load, in conjunction with the op amp output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases.

The OPAx377 in a unity-gain configuration can directly drive up to 250pF pure capacitive load. Increasing the gain enhances the ability of the amplifier to drive greater capacitive loads; see the typical characteristic plot, Small-Signal Overshoot vs Capacitive Load. In unity-gain configurations, capacitive load drive can be improved by inserting a small (10 Ω to 20 Ω) resistor, R_S, in series with the output, as shown in Figure 24. This resistor significantly reduces ringing while maintaining dc performance for purely capacitive loads. However, if there is a resistive load in parallel with the capacitive load, a voltage divider is created, introducing a gain error at the output and slightly reducing the output swing. The error introduced is proportional to the ratio R_{s}/R_{l} , and is generally negligible at low output current levels.

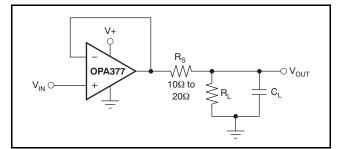


Figure 24. Improving Capacitive Load Drive



ACTIVE FILTERING

The OPA377 series is well-suited for filter applications requiring a wide bandwidth, fast slew rate, low-noise, single-supply operational amplifier. Figure 25 shows a 50kHz, 2nd-order, low-pass filter. The components have been selected to provide a maximally-flat Butterworth response. Beyond the cutoff frequency, roll-off is –40dB/dec. The Butterworth response is ideal for applications requiring predictable gain characteristics such as the anti-aliasing filter used ahead of an analog-to-digital converter (ADC).

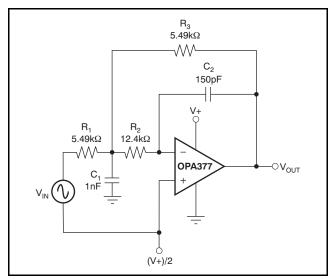
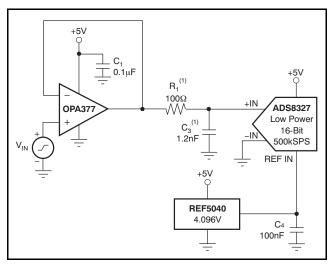


Figure 25. Second-Order Butterworth 50kHz Low-Pass Filter

DRIVING AN ANALOG-TO-DIGITAL CONVERTER

The low noise and wide gain bandwidth of the OPA377 family make it an ideal driver for ADCs. Figure 26 illustrates the OPA377 driving an ADS8327, 16-bit, 250kSPS converter. The amplifier is connected as a unity-gain, noninverting buffer.



(1) Suggested value; may require adjustment based on specific application.

(2) Initial calibration recommended.

Figure 26. Driving an ADS8327⁽²⁾



Page

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision A (October 2010) to Revision B	Page
•	Changed document status to production data	1
•	Deleted cross-reference to note 2 and shading from DCK package in Package Information table	2
•	Updated Figure 22	9

Changes from Original (February 2010) to Revision A

•	Deleted DFN from list of packages in final Features bullet	1
•	Deleted DFN package from Description section	1
•	Updated Input Bias Current vs Temperature plot	1
•	Deleted cross-reference to note 2 and shading from all packages except SC70-5 in Package Information table	2
•	Deleted DFN-8 package from Package Information table	2
•	Deleted Temperature Range, DFN-8 parameter from Electrical Characteristics table	3
•	Deleted DFN-8 pin configuration	4
•	Updated Figure 11	6



18-Oct-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OPA2377AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2377A	Samples
OPA2377AIDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OTAQ	Samples
OPA2377AIDGKT	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OTAQ	Samples
OPA2377AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2377A	Samples
OPA377AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OP377A	Samples
OPA377AIDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PAG	Samples
OPA377AIDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PAG	Samples
OPA377AIDCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PAF	Samples
OPA377AIDCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PAF	Samples
OPA377AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OP377A	Samples
OPA4377AIPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OP4377A	Samples
OPA4377AIPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OP4377A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.



PACKAGE OPTION ADDENDUM

18-Oct-2013

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

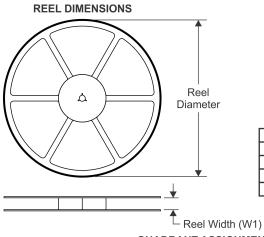
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

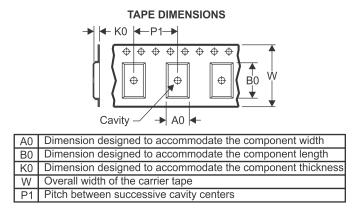
PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2377AIDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2377AIDGKT	VSSOP	DGK	8	250	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2377AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA377AIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
OPA377AIDBVR	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA377AIDBVT	SOT-23	DBV	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA377AIDBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
OPA377AIDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
OPA377AIDCKT	SC70	DCK	5	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
OPA377AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA4377AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

Texas Instruments

www.ti.com

PACKAGE MATERIALS INFORMATION

27-Aug-2013



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2377AIDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
OPA2377AIDGKT	VSSOP	DGK	8	250	366.0	364.0	50.0
OPA2377AIDR	SOIC	D	8	2500	367.0	367.0	35.0
OPA377AIDBVR	SOT-23	DBV	5	3000	223.0	270.0	35.0
OPA377AIDBVR	SOT-23	DBV	5	3000	195.0	200.0	45.0
OPA377AIDBVT	SOT-23	DBV	5	250	195.0	200.0	45.0
OPA377AIDBVT	SOT-23	DBV	5	250	223.0	270.0	35.0
OPA377AIDCKR	SC70	DCK	5	3000	195.0	200.0	45.0
OPA377AIDCKT	SC70	DCK	5	250	195.0	200.0	45.0
OPA377AIDR	SOIC	D	8	2500	367.0	367.0	35.0
OPA4377AIPWR	TSSOP	PW	14	2000	367.0	367.0	35.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
 - This drawing is subject to change without notice. Β.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
 - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated